

## Low voltage NPN power Darlington transistor

### Features

- Good  $h_{FE}$  linearity
- High  $f_T$  frequency
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

### Application

- Linear and switching industrial equipment

### Description

The device is manufactured in planar technology with “base island” layout and monolithic Darlington configuration.

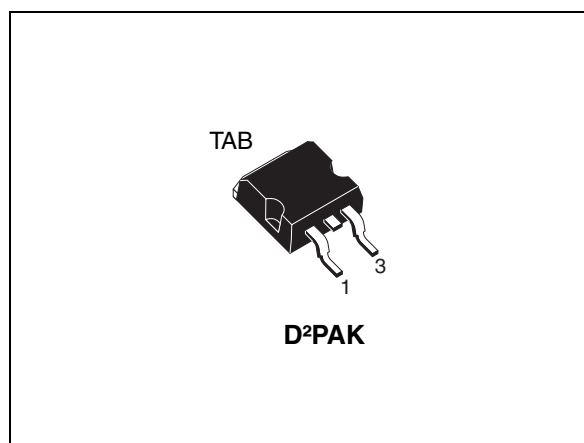


Figure 1. Internal schematic diagrams

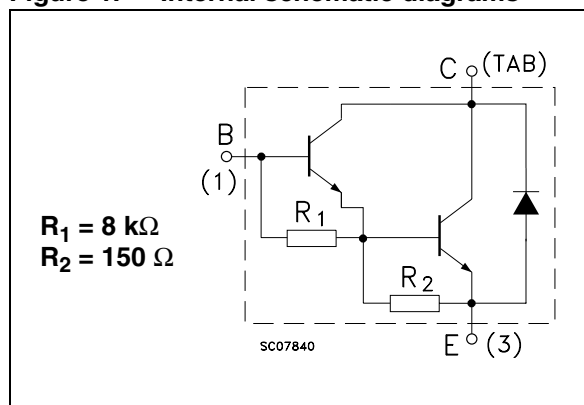


Table 1. Device summary

Order code	Marking	Package	Packaging
2STBN15D100T4	BN15D100	D <sup>2</sup> PAK	Tape and reel

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage ( $I_E = 0$ )	100	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	100	V
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ )	5	V
$I_C$	Collector current	12	A
$I_{CM}$	Collector peak current	15	A
$I_B$	Base current	0.2	A
$P_{TOT}$	Total dissipation at $T_{case} = 25\text{ °C}$	70	W
$T_{STG}$	Storage temperature	-65 to 150	°C
$T_J$	Max. operating junction temperature	150	°C

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJC}$	Thermal resistance junction-case max.	1.8	°C/W

## 2 Electrical characteristics

$T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ ; unless otherwise specified.

**Table 4. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CBO}}$	Collector cut-off current ( $I_{\text{E}} = 0$ )	$V_{\text{CB}} = 100\text{ V}$		-	100	$\mu\text{A}$
$I_{\text{CEO}}$	Collector cut-off current ( $I_{\text{B}} = 0$ )	$V_{\text{CE}} = 50\text{ V}$		-	100	$\mu\text{A}$
$I_{\text{EBO}}$	Emitter cut-off current ( $I_{\text{C}} = 0$ )	$V_{\text{EB}} = 5\text{ V}$	0.12	-	2	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ( $I_{\text{B}} = 0$ )	$I_{\text{C}} = 100\text{ mA}$	100	-		V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 0.5\text{ A}$ $I_{\text{B}} = 1\text{ mA}$		-	1.5	V
		$I_{\text{C}} = 4\text{ A}$ $I_{\text{B}} = 4\text{ mA}$		-	1.3	V
$V_{\text{BE(on)}}^{(1)}$	Base-emitter on voltage	$I_{\text{C}} = 3\text{ A}$ $V_{\text{CE}} = 3\text{ V}$		-	2.5	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 3\text{ A}$ $V_{\text{CE}} = 3\text{ V}$	750	-		
$V_{\text{F}}$	Diode forward voltage	$I_{\text{F}} = 3\text{ A}$		-	2.5	V

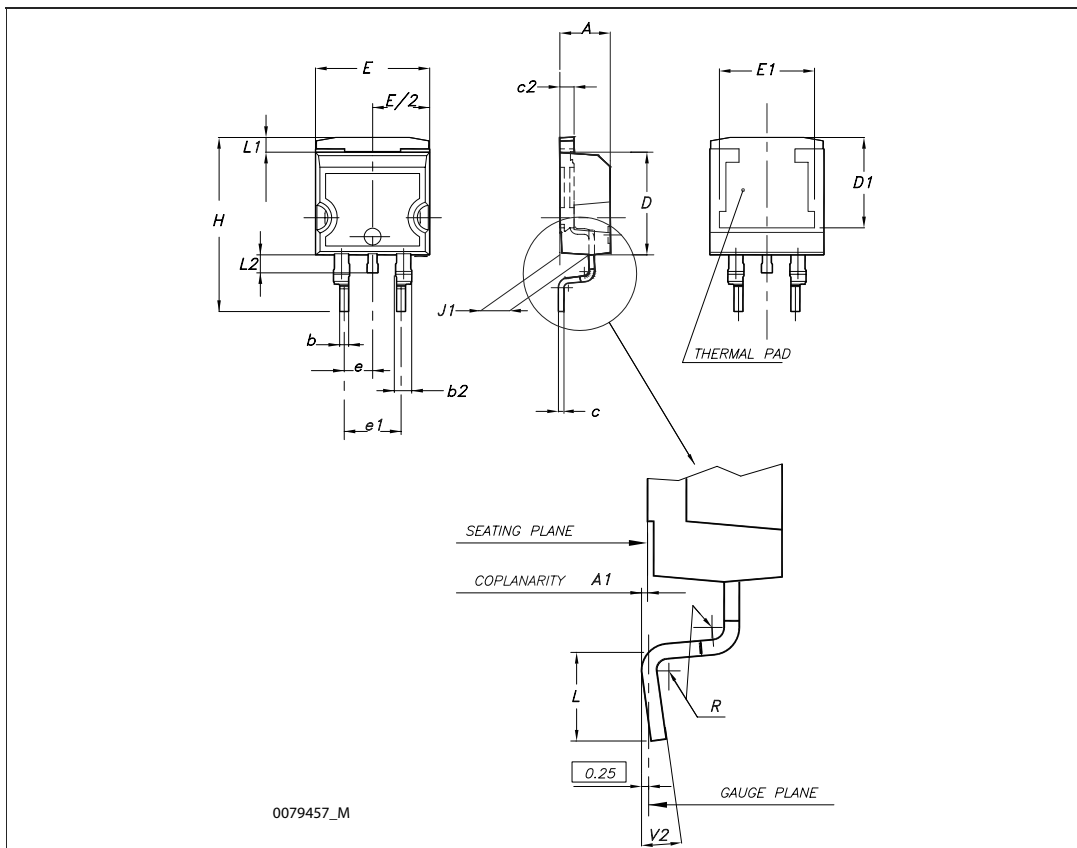
1. Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .

### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

D<sup>2</sup>PAK (TO-263) mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
e		2.54			0.1	
e1	4.88		5.28	0.192		0.208
H	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



## 4 Revision history

**Table 5. Document revision history**

Date	Revision	Changes
01-Sep-2009	1	First release.
19-Jan-2010	2	Modified <a href="#">Table 1 on page 1</a> .

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